Claims

1.(Currently Amended) A sensor, comprising: 1 a signal source that emits a physical signal; 2 a signal detector at a distance from the signal source to receive the physical signal; 3 an evaluation unit which is connected to the signal detector and evaluates the received 4 5 physical signal to determine the relative distance between the signal source and the signal detector, wherein the signal source and the signal detector are situated on separate substrate bodies; and 6 7 a control unit is connected to the signal source, the signal detector, and the evaluation unit, 8 wherein the signal source, signal detector and the evaluation unit can each be individually turned on 9 and off by the control unit.

- 1 2.(amended) The sensor of claim 1, wherein the evaluation unit includes a memory device having
- 2 characteristic information indicative of the signal source.
- 1 3.(amended) The sensor of claim 1, wherein the spatial distance between the signal source and the
- 2 signal detector is constant, and the transmission properties of the transmission channel between the
- 3 signal source and the signal detector are variable.
- 1 4.(amended) The sensor of claim 1, wherein the spatial distance between the signal source and the
- 2 signal detector is variable, and that the transmission properties of the transmission channel between
- 3 the signal source and the signal detector are constant.
- 5.(amended) The sensor of claim 3, wherein the evaluation unit is configured and arranged such
- 2 that the gas density or the transport rate or the throughflow quantity can be determined from the
- 3 relative distance.

- 1 6.(amended) The sensor of claim 4, wherein the evaluation unit is configured and arranged such
- 2 that the force acting on the sensor can be determined from the relative distance.
- 1 7.(amended) The sensor of claim 6, wherein the control unit is connected to the signal source and
- 2 controls it, and that the evaluation unit is connected to the control unit in such a way that the
- 3 information regarding the signal source can be updated with control data received from the control
- 4 unit.
- 8.(amended) The sensor of claim 1, wherein the evaluation unit and is integrated into at least one
- 2 of the substrate bodies.
- 1 9.(amended) The sensor of claim 8, wherein the evaluation unit is situated in the substrate body
- 2 directly adjoining the signal detector.
- 1 10.(amended) The sensor of claim 8, wherein the evaluation unit is integrated into the second
- 2 substrate body and the control unit is integrated into the first substrate body.
- 1 11.(amended) The sensor of claim 10, wherein the evaluation unit includes means for amplifying the
- 2 signal.
- 1 12.(amended) The sensor of claim 3, wherein the second substrate body, in which the signal detector
- 2 is situated includes a diaphragm.
- 1 13.(amended) The sensor of claim 12, further comprising a damping device to damp the diaphragm.
- 1 14.(amended) The sensor of claim 1, wherein the signal detector is sub-divided into a plurality
- 2 detector elements sufficient to provide a measure of spatial resolution.

- 1 15.(amended) The sensor of claim 14, wherein said evaluation unit includes means for processing
- 2 the spatially resolved measurement.
- 1 16.(amended) The sensor of claim 15, wherein conductor tracks are situated in the respective
- 2 substrate is used to form the signal source.
- 1 17.(New) A semiconductive sensor, comprising:
- a signal source that emits a physical signal;
- a signal detector at a distance from the signal source to receive the physical signal;
- an evaluation unit which is connected to the signal detector and evaluates the received
- 5 physical signal to determine the relative distance between the signal source and the signal detector,
- 6 wherein the signal source and the signal detector are situated on separate semiconductive substrate
- 7 bodies; and
- a control unit is connected to the signal source, the signal detector, and the evaluation unit,
- 9 wherein the signal source, signal detector and the evaluation unit can each be individually turned on
- and off by the control unit.
 - 1 18.(New) A semiconductive sensor, comprising:
 - a signal source that is mounted on a first substrate and emits a physical signal;
 - a signal detector that is mounted on a second substrate, at a distance from the signal source to
 - 4 receive the physical signal;
 - an evaluation unit which is connected to the signal detector and evaluates the received
 - 6 physical signal to determine the relative distance between the signal source and the signal detector;
 - 7 and

- a control unit that provides control signals to the signal source, the signal detector, and the
- 9 evaluation unit to selectively turn the signal source, the signal detector, and the evaluation unit on
- 10 and off.